Monolithic Digital IC

LB1896

3-phase Brushless Motor Driver for CD-ROM Spindle Drive Use

Overview

The LB1896 is a 3-phase brushless motor driver IC that is ideal for driving CD-ROM spindle motors.

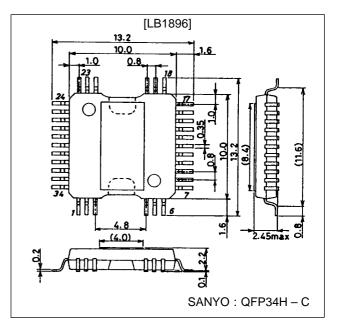
Functions and Features

- 120 ° voltage linear technique
- V-type control voltage
- · Switchable control gain
- Control, noncontrol, acceleration/deceleration mode select pins built in.
- Start/Stop pin built in, Hall bias built in.

Package Dimensions

unit : mm

3219-QFP34H-C



Specifications

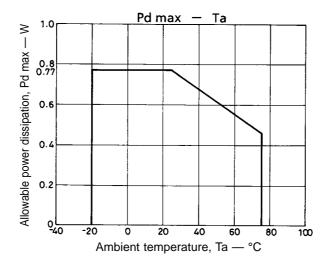
Absolute Maximum Ratings at Ta = $25 \circ C$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} 1 max		20	V
	V _{CC} 2 max		7.0	~
Applied output voltage	V _{OU, V, W}		20	V
Output current	lout		1.2	А
Allowable power dissipation	Pd max	Independent IC	0.77	W
Operating temperature	Topr		-20 to +75	°C
Storage temperature	Tstg		-55 to +150	°C

Operating Conditions at Ta = 25 \circ C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V _{CC} 1		5 to 18	V
Supply voltage	V _{CC} 2	$V_{CC}1 \ge V_{CC}2$	4.3 to 6.5	V
V _{Cref} input voltage	V _{Cref}		V _{CC} 2/2 ±1.0	V
V _{NS} input voltage	V _{NS}		0 to V _{CC} 2 –1.0	V

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Electrical Characteristics at Ta = 25 °C, $V_{\rm CC}1$ = 12 V, $V_{\rm CC}2$ = 5 V

Parameter	Symbol	Conditions	min	typ	max	Unit
Supply current 1	I _{CC} 1	V_{C} = open, V_{Cref} = open, R_{L} = ∞ , $V_{S/S}$ = 5 V		17	30	mA
Supply current 2	I _{CC} 2	V_{C} = open, V_{Cref} = open		7.5	10.5	mA
Supply current 3	I _{CC} 3	V_C = open, V_{Cref} = open, R_L = ∞ , $V_{S/S}$ = 0 V, (I _{CC} of V _{CC} 1)		0.9	3	mA
[Drive block]						
Output saturation voltage	V _{O(sat)} 1	I _{OUT} = 0.4 A, sink + source		1.6	2.2	V
Ouput saturation voltage	V _{O(sat)} 2	I _{OUT} = 0.8 A, sink + source		2.0	3.0	V
Output TRS sustaining voltage	V _{O(sus)}	I _{OUT} = 20 mA	20			V
Output static voltage	V _{OQ}	V_{C} = 2.5 V, V_{Cref} = 2.5 V	5.7	6.0	6.3	V
Hall amplifier input offset voltage	V _{H offset}		-5		+5	mV
Hall amplifier input bias current	I _{H bias}			1	5	μA
Hall amplifier common-mode input voltage range	V _{Hch}		1.3		2.2	V
Hall input/output voltage gain	G _{VHO}		40	43	46	dB
Control/output drive gain 1	G _{VCO} 1	RZ1 = RZ2, GC1 = L, GC2 = L	26	29		dB
Control/output channel difference 1	∆G _{VCO} 1	RZ1 = RZ2, GC1 = L, GC2 = L	-1.5		+1.5	dB
Control/output drive gain 2	G _{VCO} 2	RZ1 = RZ2, GC1 = L, GC2 = H	32	35		dB
Control/output channel difference 2	∆G _{VCO} 2	RZ1 = RZ2, GC1 = L, GC2 = H	-1.9		+1.9	dB
Input dead zone voltage	V _{DZ}	RZ1 = RZ2, GC1 = L, GC2 = L V _O (voltage between out and out) = 0.1 V	±13	±38	±55	mV
Input bias current 1	IB SERVO	$V_{\rm C} = 1.0 \ {\rm V}$			500	nA
Input bias current 2	I _{B n.s}	V _{NS} = 1.0 V			500	nA
S/S pin high voltage	V _{S/S H}	Input is CMOS level	4			V
S/S pin low voltage	V _{S/S L}	Note) S/S pin Vth = V _{CC} 2/2			1	V
Gain control 1 high voltage	V _{GC1 H}	Input is at CMOS level.	4			V
Gain control 1 low voltage	V _{GC1 L}	Note) GC1 pin Vth = 2.0 V			1	V
Gain control 2 high voltage	V _{GC2 H}	Input is at CMOS level.	4			V
Gain control 2 low voltage	V _{GC2 L}	Note) GC2 pin Vth = 2.0 V			1	V
S/S pin input current	I _{S/S}	Input voltage = 5 V		50	100	μA
Gain control 1, 2 current	I _{GC}	Input voltage = 5 V		53	110	μA
Rotation output saturation voltage	V _{(sat) H.FG}	$I_0 = -5 \text{ mA}$		0.24	0.5	V
Rotation output saturation sustaining voltage	V _(sus) H.FG				7	V
Hall bias voltage	V _H ±	I _O = 5 mA, R _H = 200 Ω	0.7	0.97	1.2	V
CTRL pin high voltage	V _{CTRL} H	Common for CTRL1 and CTRL2 input CMOS level	4			V
CTRL pin low voltage	V _{CTRL L}	Note) CTRL pin Vth = 2.5 V			1.0	V
CTRL input current	ICTRL	Input voltage = 5 V		53	110	μA
TSD operation voltage	TSD	Design target	150	180	210	°C
TSD hysteresis	ΔTSD	Design target		15		°C

Note) Vth is a design target and not measured.

Mode Switching Truth Table

CTRL0	CTRL1	Mode
L	L	Control
L	Н	Noncontrol
Н	L	Acceleration
Н	Н	Deceleration

L = 0 to 1.0 V

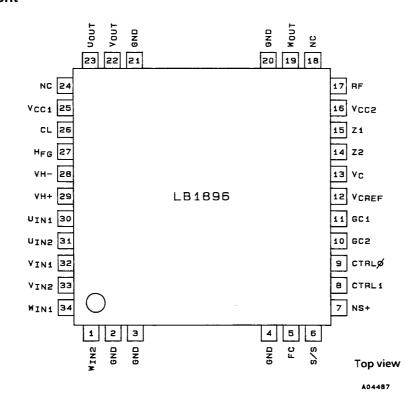
H = 4.0 V or more

Hall Logic Truth Table

		Hall input			F/R Control	
	Source \rightarrow Sink	U _{IN}	V _{IN}	W _{IN}		
1	$W \rightarrow V$	Н	н		Forward	
	$V \rightarrow W$				Reverse	
2	$W \rightarrow U$			L	Forward	
2	$U\toW$	Н	L		Reverse	
3	$V \rightarrow W$	L	L	н	Forward	
5	$W \to V$				Reverse	
4	$\begin{array}{c} U \rightarrow V \\ V \rightarrow U \end{array}$	L	н	L	Forward	
4					Reverse	
5	$V \rightarrow U$	Н	L	н	Forward	
5	$U\toV$				Reverse	
6	$U\toW$	L	н		Forward	
	$W\toU$			H	Reverse	

An input is considered to be HIGH when $U_{IN}1>U_{IN}2$, $V_{IN}1>V_{IN}2$, and $W_{IN}1>W_{IN}2$ by 0.2 V or more. Forward when $V_C>V_{Cref}$ Reverse when $V_C<V_{Cref}$

Pin Assignment



Pin Functions

Pin No.	Pin Name	Pin Voltage	Equivalent Circuit Diagram	Pin Function
3, 4 20, 21	Frame GND			Frame GND. GND must be shared.
2	GND			GND
23 22 19	U _{OUT} V _{OUT} W _{OUT}		OVCC1 (23) (19) ORf A04490	Output pins. Motor connection
17	Rf		OVCC2 17) R f 404481	Output Tr GND. A resistor can be connected between this pin and GND to sense the output current as a voltage drop to provide for overcurrent protection.
18, 24	NC			Idle pins.
16	V _{CC} 2	4.3 to 6.5 V		 Power supply for blocks other than the output block. This supply should be kept stable to prevent ripple and noise from entering this pin.
15 14	Z1 Z2		OVCC2 OVCC2 OVCC2 OVCC2 OVCC2 OCD OCD OCD OCD OCD	 First-stage amplifier gain setting resistors. Z1 and Z2 normally range from several tens of kΩ to several hundreds of kΩ. The gain is about 6 dB.
13 12	V _C V _{Cref}	V _{CC} 2/2 ±1.0	VCC2 VCC2 VCC2 (1) (1) (1) (1) (1) (1) (1) (1)	 V_C is the speed control pin. Forward when V_C > V_{Cref}. Reverse when V_C < V_{Cref}. V_C is used to control the output voltage. V_{Cref} determines the motor control stop voltage. V_{CC}2/2 in normal use.
11 10	GC1 GC2	0 to V _{CC} 2	VCC2	 Input/output gain switching pins. GC1 is for first-stage amplifier Z1/Z2 switching. When GC1 is LOW, Z1 is selected; when HIGH, Z2 is selected. GC2 is for next-stage amplifier switching.

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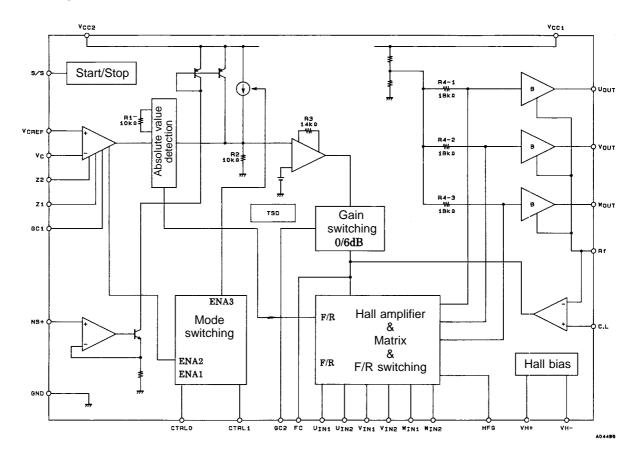
Pin No.	Pin Name	Pin Voltage	Equivalent Circuit Diagram	Pin Function
9 8	CTRL¢ CTRL1	0 to V _{CC} 2	VCC2 VCC2 () (8) (7) (7) (7) (7) (7) (7) (7) (7) (7) (7	 Operation mode switching pins. Refer to the Mode Switching Truth Table for selection of control, acceleration, or deceleration.
7	NS+	0 to V _{CC} 2 – 1 V	VCC2	 Input pin at noncontrol mode. The input-output gain is 14 dB. (GC2: LOW) Motor stops when V_{NS} = 0 V.
6	S/S	0 to V _{CC} 2	€	 When the S/S pin is HIGH, START; when LOW, STOP. The threshold is V_{CC}2/2.
5	FC		5 5 5 6 6 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7	Connect a capacitor between this pin and GND to reduce the input/output gain frequency response and to stop the oscillator.
1 34 33 32 31 30	W _{IN} 2 W _{IN} 1 V _{IN} 2 V _{IN} 1 U _{IN} 2 U _{IN} 1	1.3 to 2.2 V	34 1 32 1 30 1 1 1 33 33 30 1 1 1<	W-phase Hall device input pins. Logic "H" represent $W_{IN}1 > W_{IN}2$ V-phase Hall device input pins. Logic "H" represent $V_{IN}1 > V_{IN}2$ U-phase Hall device input pins. Logic "H" represent $U_{IN}1 > U_{IN}2$

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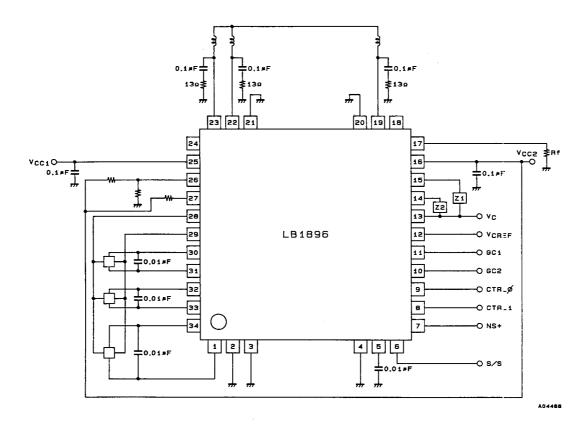
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Pin No.	Pin Name	Pin Voltage	Equivalent Circuit Diagram	Pin Function
29 28	VH+ VH–	2.4 V 1.4 V	CC2 (28) (28) (28) (29) (29) (29) (29) (29) (29) (29) (29	 Hall device power supply pins. A voltage difference of 1.0 V is developed between VH+ and VH
27	H.FG	0 to V _{CC} 2		 Hall FG pin. The Hall waveform is converted into a pulse signal and then used as the FG pulse signal.
26	CL	0 to V _{CC} 2	ZG W W CC2 VCC2 VCC2 A04502	 When the Rf pin voltage becomes equal to the C_L pin voltage, the current limiter operate. The C_L voltage is determined externally.
25	V _{CC} 1	5 to 18 V		 Power supply for output block. This supply should be kept stable to prevent ripple and noise from entering this pin.

Block Diagram



Sample Application Circuit



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